ESH3B-M3, ESH3C-M3, ESH3D-M3

Vishay General Semiconductor

COMPLIANT

HALOGEN

FREE

Surface-Mount Ultrafast Plastic Rectifier



SMC (DO-214AB)



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | | |
|-------------------------|---------------------|--|--|--|--|
| I _{F(AV)} | 3.0 A | | | | |
| V _{RRM} | 100 V, 150 V, 200 V | | | | |
| t _{rr} | 25 ns | | | | |
| V _F | 0.90 V | | | | |
| T _J max. | 175 °C | | | | |
| Package | SMC (DO-214AB) | | | | |
| Circuit configuration | Single | | | | |

FEATURES

- Glass passivated pellet chip junction
- · Ideal for automated placement
- Ultrafast recovery times for high efficiency
- Low forward voltage, low power loss
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converter and inverter for both consumer, and automotive.

MECHANICAL DATA

Case: SMC (DO-214AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test **Polarity:** color band denotes cathode end

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | |
|--|-----------------------------------|-------------|-------|-------|------|
| PARAMETER | SYMBOL | ESH3B | ESH3C | ESH3D | UNIT |
| Device marking code | | EHB | EHC | EHD | |
| Maximum repetitive peak reverse voltage | V _{RMM} | 100 | 150 | 200 | |
| Maximum RMS voltage | V_{RMS} | 70 | 105 | 140 | V |
| Maximum DC blocking voltage | V_{DC} | 100 | 150 | 200 | |
| Maximum average forward rectified current (fig. 1) | I _{F(AV)} | 3.0 | | | А |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | I _{FSM} | 125 | | | |
| Operating junction and storage temperature range | T _J , T _{STG} | -55 to +175 | | | °C |



ESH3B-M3, ESH3C-M3, ESH3D-M3

Vishay General Semiconductor

| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | |
|---|---|-------------------------|-------------------------------|-------|------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | VALUE | UNIT | |
| Maximum instantaneous forward voltage | I _F = 3 A | | V _F ⁽¹⁾ | 0.90 | ٧ | |
| Maximum DC reverse current | | T _A = 25 °C | 1 | 5.0 | μΑ | |
| at rated DC blocking voltage | | T _A = 125 °C | I _R | 150 | | |
| Maximum reverse recovery time | $I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$ | | t _{rr} | 25 | | |
| Typical reverse recovery time | $I_F = 3 A, V_B = 30 V,$ | T _J = 25 °C | - t _{rr} | 40 | ns | |
| | dl/dt = 50 A/μs, I _{rr} = 10 % I _{RM} | T _J = 100 °C | | 55 | | |
| Typical stored charge | IF - 071, VR - 00 V, | T _J = 25 °C | Q _{rr} | 25 | nC | |
| | | T _J = 100 °C | | 60 | | |
| Typical junction capacitance | 4.0 V, 1 MHz | | CJ | 70 | pF | |

Note

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | |
|---|----------------------|------------------------|--|------|------|
| PARAMETER | SYMBOL | ESH3B ESH3C ESH3D UNIT | | | |
| Typical thermal resistance | R _{0JA} (1) | 50 | | | °C/W |
| Typical thermal resistance | R _{eJL} (1) | 15 | | C/VV | |

Note

(1) Units mounted on PCB with 12.0 mm x 12.0 mm land areas

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|-----------------|------------------------|---------------|------------------------------------|--|--|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| ESH3D-M3/57T | 0.211 | 57T | 850 | 7" diameter plastic tape and reel | | |
| ESH3D-M3/9AT | 0.211 | 9AT | 3500 | 13" diameter plastic tape and reel | | |

1000

Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

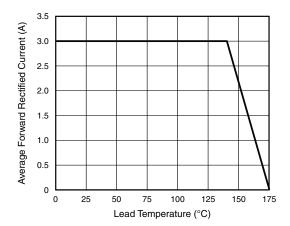


Fig. 1 - Maximum Forward Current Derating Curve

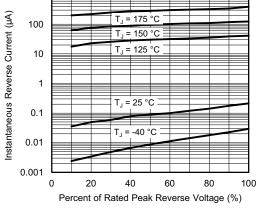


Fig. 4 - Typical Reverse Leakage Characteristics

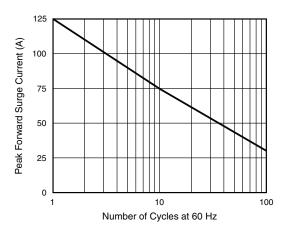


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

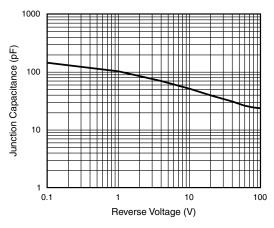


Fig. 5 - Typical Junction Capacitance

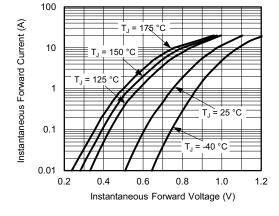


Fig. 3 - Typical Instantaneous Forward Characteristics

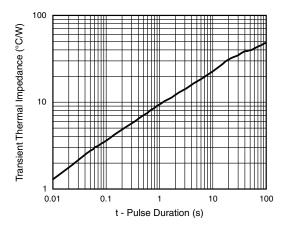


Fig. 6 - Typical Transient Thermal Impedance

0.030 (0.76)

ESH3B-M3, ESH3C-M3, ESH3D-M3

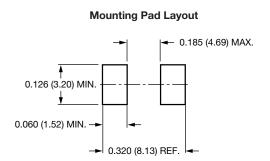
Vishay General Semiconductor

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

0.126 (3.20) 0.114 (2.90) 0.280 (7.11) 0.260 (6.60) 0.006 (0.152) 0.000 (0.152)

0.320 (8.13) 0.305 (7.75)

0 (0)





Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.